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"Bonding in Transition Metal Silyl Dimers.
Molecular Orbital Theory"

by

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Claire A. Tessier-Youngs, and Wiley J. Youngs

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Department of Chemistry
Case Western Reserve University
Cleveland, Ohio 44106

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Chemistry Department, Case Western Reserve University
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Abstract

Molecular orbital studies of $\text{Mn}_2(\text{CO})_8(\text{Si}(\text{C}_6\text{H}_5)_2)_2$ and $\text{Pt}_2(\text{H}_3\text{P})_4(\text{SiC}_6\text{H}_5\text{Cl})_2$ have been made by interacting disilene fragments with transition metal dimers. In the former complex, it is found that the Mn-Mn distance is close to the sum of the atomic radii because the Mn-Mn bond order is 1. This leads to a long Si-Si distance and allows strong Si-Mn bond formation. In the latter complex, the Pt-Pt bond order is 0, so the disilene, with Si-Si bond intact, binds to the Pt atoms by means of ordinary π donation and back-donation to π^* . Based on these findings, the M-M and Si-Si distances in other known transition metal-silyl four-membered rings are discussed.

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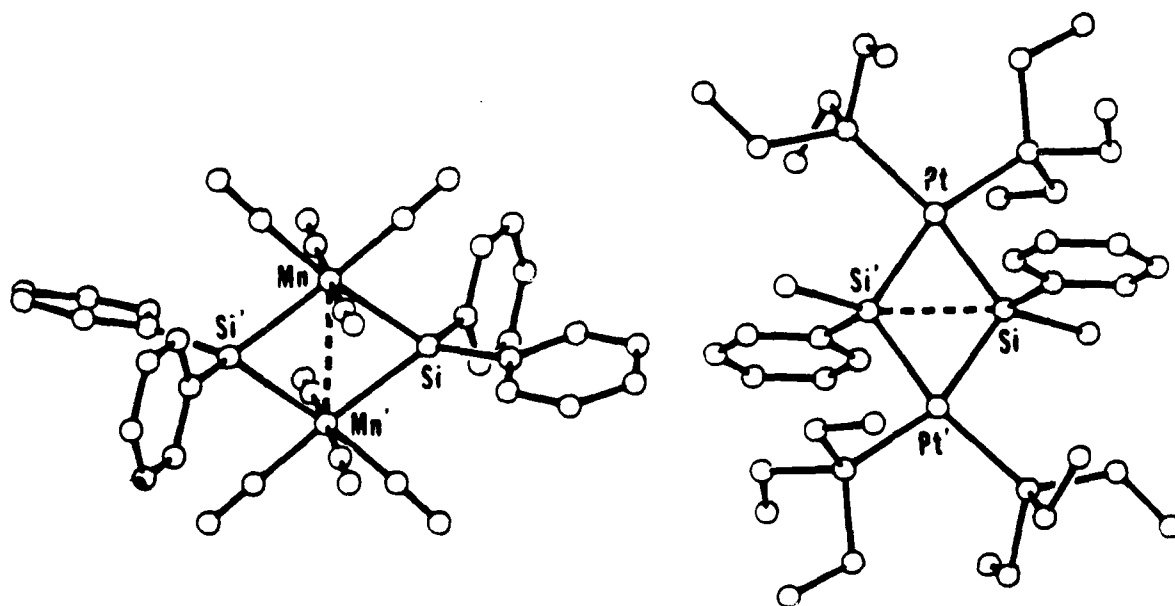
The applications of polysilanes¹ have produced considerable interest in their synthesis by transition metal catalysis.²⁻⁴ Attempts to isolate compounds from such catalytic mixtures have led to the isolation of bimetallic (M_2Si) or dimeric (MSi)₂ transition metal silyl complexes.^{3,4} Several different types of structures have been found for metal-silyl dimers³⁻¹² but no attempt has been made to describe the bonding in these species. To address this need and to begin to understand structure/bonding/catalytic activity relationships we have undertaken a theoretical study of two types of dimeric metal-silyl complexes.

With the exception of $Ti_2(C_5H_5)_4H_2(Si(C_6H_5)H)_2$,^{4a} and the recently synthesized series $[((C_2H_5)_3P)_2Pt(Si(C_6H_5)X)(Si(C_6H_5)Y)Pt((C_2H_5)_3)_2]$ (1a, X=Y=H; 1b, X=Y=Cl; and 1c, X=H, Y=Cl),³ the planar transition metal-silyl four-membered rings of the form $M_2L_nL_m(SiR_2)_2$ are characterized by long Si-Si distances, short M-M distances (Table I), and acute M-Si-M angles.⁵⁻¹¹ The consistency of the M-Si-M (70-75°) and Si-M-Si (105-110°) angles in this type of structure is remarkable in light of the variety of metals, ligands, and silyl substituents present in these complexes. The two exceptions possess two different structures. In the complex $Ti_2(C_5H_5)_4H_2(Si(C_6H_5)H)_2$, the ring is roughly rectangular with no short cross-ring distances. The complexes 1a-c possess short cross-ring Si-Si distances (within the known range of Si-Si bonds)³, long M-M distances, and acute Si-M-Si angles.¹² The short cross-ring Si-Si distances observed in the $[R_2SiX]_2$ four-membered rings, where X is a bridging main group moiety¹³, have been discussed in terms of electron pair repulsions on X atoms, strong Si-X bonds, and

unsupported Si-Si π -bonds.¹⁴ The nature of Si-Si bonding (if any) in the transition metal silyl four-membered rings with short Si-Si distances and the role of metal d electrons have, to our knowledge, not been addressed before. In particular, this study probes whether or not the complexes with short Si-Si cross-ring distances can be described as disilenes bound to two metal centers. The recent observation that bulky disilenes can form complexes with single metal centers,¹⁵ and the conclusion of a theoretical study that a disilene should be a better σ -donor and π acceptor than an alkene,^{14a} lend support to the proposed description.

A molecular orbital study is made of two complexes (Fig. 1). The first, $\text{Mn}_2(\text{CO})_8(\text{Si}(\text{C}_6\text{H}_5)_2)_2$,⁷ has Mn-Mn and Si-Si distances of 2.871 and 3.852 Å, respectively. The second one, $\text{Pt}_2((\text{C}_2\text{H}_5)_3\text{P})_4(\text{Si}(\text{C}_6\text{H}_5)\text{Cl})_2$, (1b) has respective Pt-Pt and Si-Si distances of 3.973 and 2.602 Å.³ In the Mn complex the metal-metal distance is close to the sum of two atomic radii, just 0.17 Å greater, and the Si-Si distance is much larger than the bulk single bond distance of 2.35 Å.¹⁶ In the Pt complex the metal-metal distance is much greater than the sum of two atomic radii, 2.78 Å, and the Si-Si distance is just 0.25 Å greater than the single bond value. The theoretical evaluation of the metal-metal and Si-Si bond orders is an important aspect of the present study.

The atom superposition and electron delocalization molecular orbital (ASED-MO) theory^{17,18} is used. Because the experimentally determined equilibrium structures are available, no structure

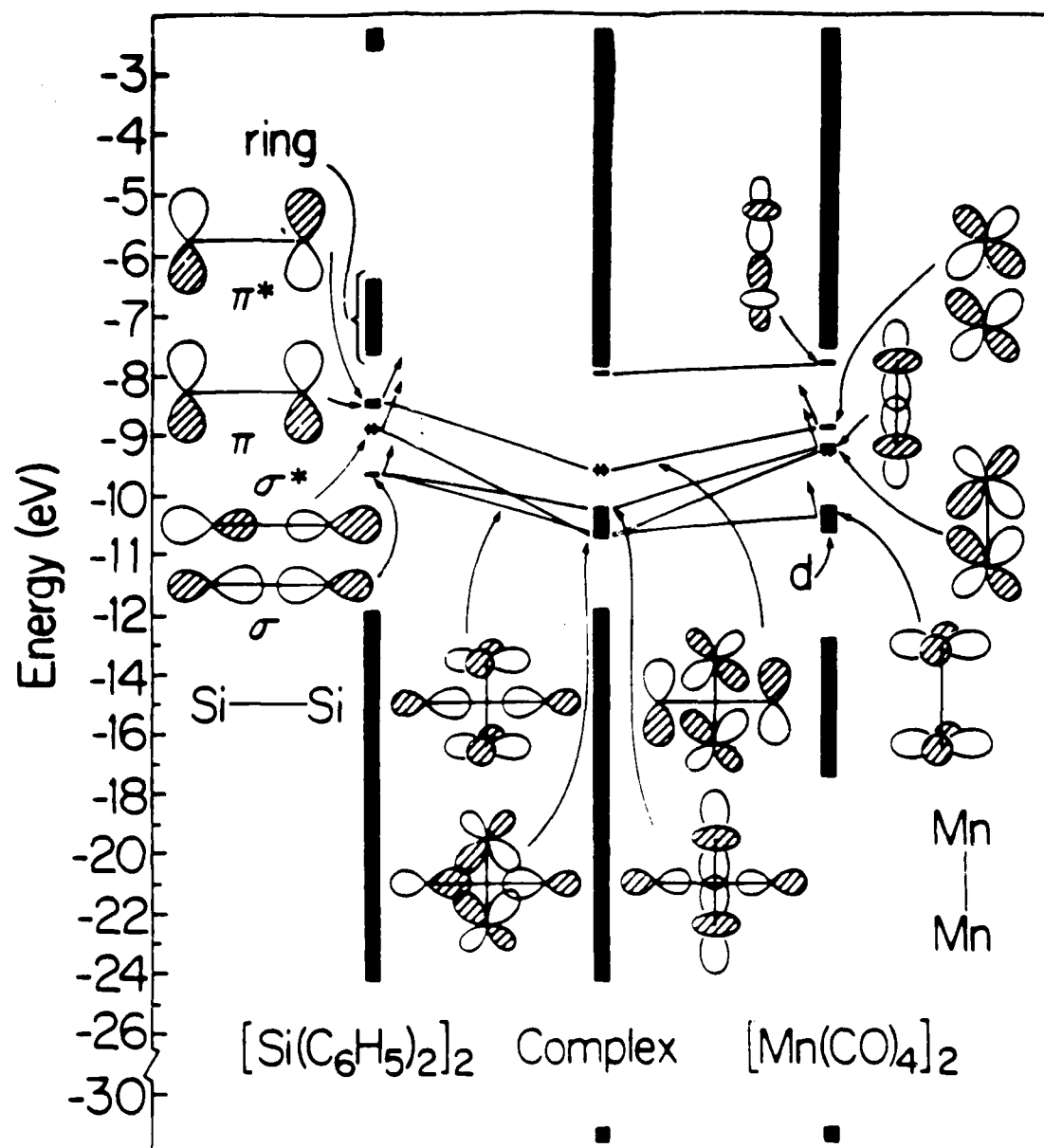


1. Structures of $\text{Mn}_2(\text{CO})_8(\text{Si}(\text{C}_6\text{H}_5)_2)_2$ and $\text{Pt}_2(\text{P}(\text{C}_2\text{H}_5)_3)_4(\text{Si}(\text{C}_6\text{H}_5)\text{Cl})_2$ (1b).

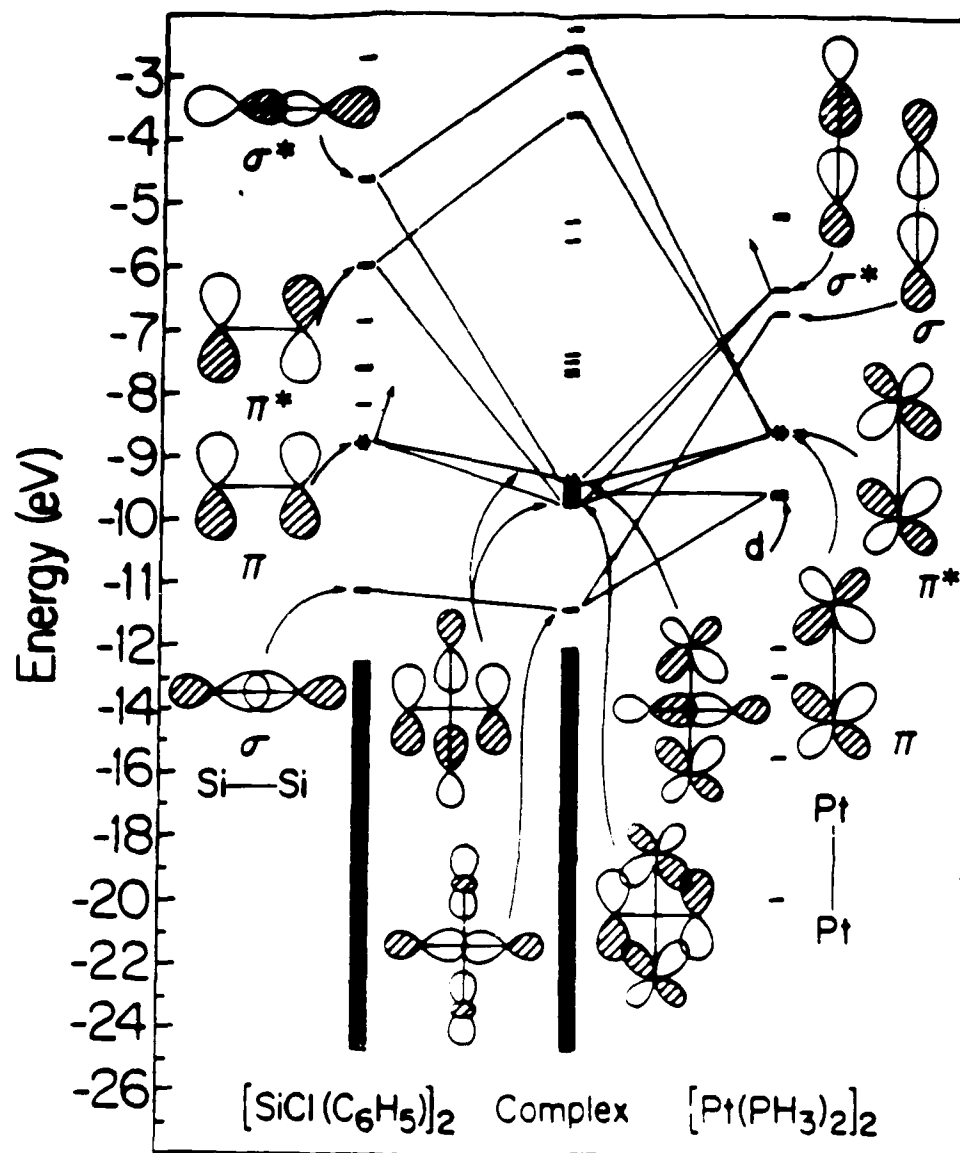
optimizations are required. The analysis is based on a molecular orbital correlation diagram for each complex. The complete Mn complex is employed in the calculation and the Pt complex is simplified by replacing the 12 Et groups attached to the two P atoms by 12 H atoms. The ASED-MO parameters, which are taken from the literature as discussed in Ref. 18, are given in Table II.

Bonding of the Mn complex is examined first. The bonding together of the $[\text{Si}(\text{C}_6\text{H}_5)_2]_2$ and $[\text{Mn}(\text{CO})_4]_2$ fragments is shown in the correlation diagram of Fig. 2. Examination of the ten 3d molecular orbital energy levels for $[\text{Mn}(\text{CO})_4]_2$ reveals three empty orbitals, one of which is Mn-Mn bonding while the other two are antibonding. Each Mn is d^7 . Altogether, four bonding orbitals and three antibonding orbitals are occupied, so the formal metal bond order of the fragment is 1. The relatively short Mn-Mn bond forces a long Si-Si distance for optimal Si-Mn bonding overlap. Because of the large Si-Si distance, the $\sigma-\sigma^*$ and $\pi-\pi^*$ splittings are very small, so the fragment could be viewed as two weakly interacting silylene molecules. Nevertheless, σ and π notation is used. As the diagram shows, the Mn disilene σ , σ^* , π , and π^* (or the four silylene lone pair and empty p orbitals) all have bonding overlaps with metal fragment orbitals, giving a substantial Si-Mn Mulliken overlap population of 0.27. Because the disilene fragment is a 4 electron donor, only the 3d σ^* orbital remains empty so the Mn-Mn bond order is still 1 and each Mn becomes d^9 .

Now consider the bonding in the Pt complex 1b shown in Fig. 3. In the Pt_2 fragment all ten d molecular orbitals are occupied,



2. Bonding of disilene to Mn_2 dimer.



3. Bonding of disilene to Pt_2 dimer.

so the Pt-Pt bond order is 0 and each Pt is d^{10} . The Si-Si bond is intact in this complex because this structure allows strong Si-Pt bonding overlap and the σ and π electronic structure shows the expected splittings. Note that the empty σ_S and σ_S^* orbitals in the Pt_2 fragment lie low in energy and are accessible for bonding to the Si_2 fragment. In the complex the Si-Si π orbital donates to the Pt-Pt σ_{sp}^* orbital and the Si-Si σ orbital donates to the Pt-Pt σ_{sp} orbital; these donation interactions have no net influence on the Pt-Pt bond order. There is some back-donation from the Pt_2 fragment d set to the Si-Si π^* and σ^* orbitals. The Si-Si Mulliken overlap population for 1b is 0.27 and the Si-Pt overlap population is 0.52, indicating strong Si-Si and Si-Pt bonding. The Pt-Pt bond order remains 0, which explains the long Pt-Pt distance, and each Pt remains d^{10} .

Based on these two studies, generalizations to the other metal-silyl four-membered rings are possible. Consider the number of d electrons on each M of the M_2 fragments for the remaining complexes in Table I: $Pt_2(P(C_6H_{11})_3)_2H_2(Si(CH_3)_2)_2[d^9]$; $Ru_2(Si(CH_3)_3)_2(CO)_6(Si(CH_3)_2)_2[d^7]$; $Re_2(CO)_7H_2(Si(C_2H_5)_2)_2[d^6]$; $W_2(CO)_8H_2(Si(C_2H_5)_2)_2[d^5]$; $Re_2(CO)_6H_4(SiC_2H_5)_2[d^5]$; $Ti_2(C_5H_5)_4H_2(Si(C_6H_5)H)_2[d^1]$. According to Fig. 3 the first Pt complex has a Pt-Pt bond order of 1 because the σ_{sp}^* becomes the LUMO, so there is a short Pt-Pt distance. The Ru complex has a metal bond order of 1 like the Mn complex and the first Re complex has a metal bond order of 2 while the other Re and the W complexes have a metal bond order of 1, as may be seen in Fig. 2. In the Ti complex all distances are long and it is expected that the 1s

orbitals of the two H atoms, which bridge opposing Si-Ti bonds, stabilize the Ti-Ti d-d π^* + Si-Si p-p π^* orbital so that it is occupied. This ensures long Si-Si and Ti-Ti distances and at the same time provides Si-Ti bonding.

Complexes with d⁸ metal centers in the M₂ fragments present an interesting situation. According to Fig. 2 the fragment M-M bond order will be 2 but in the complex it will be 0. Thus a short M-M bond seems to be excluded, and therefore the Fe-Fe distance in Fe₂(CO)₈(Si(C₆H₅)₂)₂ is likely to be long. This complex has been made but not structurally characterized.¹⁹

Acknowledgment is made to the Donors of the Petroleum Research Fund, Administered by the American Chemical Society, and the Office of Naval Research for support of this work.

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12. a. The complex $\text{Ti}_2(\text{C}_5\text{H}_5)_2(\text{SiH}_2)_2$ also possesses a short cross-ring Si-Si distance (2.69 Å) and an acute Si-M-Si angle.^{12b} The report of this complex provided no details on how the hydrides on silicon were located and no data other than elemental analyses for the presence or number of these hydrides. Because this complex is much less well charac-

terized than other metal-silicon four-membered rings, we have chosen not to include it in discussions of bonding.

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Figure Captions

1. Structures of $\text{Mn}_2(\text{CO})_8(\text{Si}(\text{C}_6\text{H}_5)_2)$ and $\text{Pt}_2(\text{P}(\text{C}_2\text{H}_5)_3)_4(\text{Si}(\text{C}_6\text{H}_5)\text{Cl})_2(1b)$.
2. Bonding of disilene to Mn_2 dimer.
3. Bonding of disilene to Pt_2 dimer.

Table I. Structures of transition metal-silyl four-membered rings based on data in references 1-8. d electron count is for M in M_2 fragment.

Compound	Reference	d^n	distance (Å)		angle (deg)	
			M-M	Si-Si	Si-M-Si	M-Si-M
$Pt_2(C_2H_5)_3P)_4(Si(C_6H_5)Cl)_2$	3	d^{10}	3.973	2.602	67	114
$Pt_2(P(C_6H_{11})_3)_2H_2(Si(CH_3)_2)_2$	5	d^9	2.708	3.896	110	70
$Ru_2(Si(CH_3)_3)_2(CO)_6(Si(CH_3)_3)_2$	6	d^7	2.959	3.886	105	75
$Mn_2(CO)_8(Si(C_6H_5)_2)_2$	7	d^7	2.871	3.852	107	73
$Re_2(CO)_7H_2(Si(C_2H_5)_2)_2$	8	d^6	3.052	4.075	106	74
$Re_2(CO)_6H_4(Si(C_2H_5)_2)_2$	9	d^5	3.084	4.023	105	75
$W_2(CO)_8H_2(Si(C_2H_5)_2)_2$	10	d^5	3.183	4.225	106	74
$Ti_2(C_5H_5)_4H_2(Si(C_6H_5)H)_2$	4a	d^1	3.890	3.820	88	91
					89	90

Table II. Valence orbital ionization potentials, IP(eV) and Slater exponents, ζ (a.u.) used in the

ASED-MO calculations.

atom	s			p			d					
	n ^a	IP	ζ	n	IP	ζ	n	IP	ζ_1	c_1^b	ζ_2	c_2^b
Mn	4	7.634	1.65	4	5.15	1.35	3	9.0	5.15	0.5139	1.70	0.6929
Pt	6	9.0	2.55	6	4.96	2.25	5	9.6	6.013	0.6559	2.396	0.5715
Sn	3	13.46	1.634	3	8.15	1.428						
P	3	16.15	1.881	3	10.49	1.629						
Cl	3	25.54	2.356	3	12.97	2.039						
O	2	28.48	2.246	2	13.62	2.227						
C	2	16.59	1.658	2	11.26	1.618						
H	1	13.6	1.2									

^aprincipal quantum number.

^blinear coefficients for double-zeta d Slater orbitals.